VS-GBPC.. Series

Vishay Semiconductors

Single Phase Bridge (Power Modules), 25 A, 35 A





GBPC...A

GBPC...W

PRODUCT SUMMARY				
I _O	25 A, 35 A			
V _{RRM}	200 V to 1200 V			
Package	GBPCA, GBPCW			
Circuit	Single phase bridge			

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FEATURES

• Universal, 3 way terminals: push-on, wrap around or solder



- High thermal conductivity package, electrically insulated case
 RoHS COMPLIANT
- · Positive polarity symbol molded on the plastic case
- Center hole fixing
- Glass passivated diode chips
- Excellent power/volume ratio
- Nickel plated terminals solderable using lead (Pb)-free solder; Solder Alloy Sn/Ag/Cu (SAC305); Solder temperature 260 °C to 275 °C
- Wire lead version available
- UL E300359 approved
- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES GBPC25	VALUES GBPC35	UNITS	
1		25	35	A	
IO	T _C	60	55	۵°	
I _{FSM}	50 Hz	400	475	•	
	60 Hz	420	500	A	
l ² t	50 Hz	790	1130	A ² s	
1-1	60 Hz	725	1030	Ars	
V _{RRM}	Range	200 to 1200		V	
TJ		-55 to +150		°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK AC REVERSE VOLTAGE T _J = T _J MAXIMUM V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK AC REVERSE VOLTAGE $T_J = T_J$ MAXIMUM V	$I_{RRM} MAXIMUM AT RATED V_{RRM} T_J = T_J MAXIMUM mA$	I _{RRM} MAXIMUM DC REVERSE CURRENT AT T _J = 125 °C μA	
	02	200	275		500	
VS-GBPC25A ⁽¹⁾	04	400	500			
VS-GBPC35A (1)		600	725	2		
VS-GBPC25W	08	800	900	2		
VS-GBPC35W	10	1000	1100			
	12	1200	1300			

Note

⁽¹⁾ See Ordering Information table at the end of datasheet

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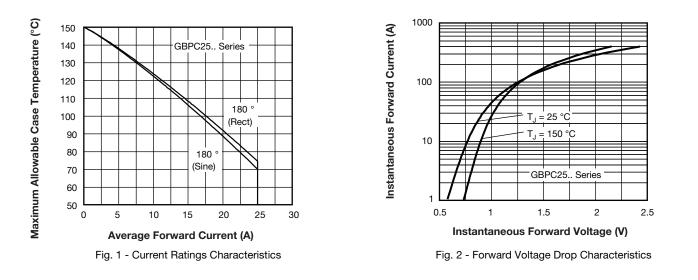


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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES GBPC25	VALUES GBPC35	UNITS
	I _O	Resistive or inductive load		25	35	A	
Maximum DC output current at case temperature		Capacitive load		20	28		
					60	55	°C
	I _{FSM}	t = 10 ms	No voltage	-	400	475	A
Maximum peak, one-cycle non-repetitive forward current		t = 8.3 ms	reapplied		420	500	
		t = 10 ms	100 % V _{BBM}		335	400	
		t = 8.3 ms	reapplied	Initial T. – T. maximum	350	420	
	l ² t	t = 10 ms	No voltage	Initial $T_J = T_J$ maximum	790	1130	A ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		725	1030	
		t = 10 ms	100 % V _{RRM}		560	800	
		t = 8.3 ms	reapplied		512	730	
Maximum I ² √t for fusing	l²√t	l^2t for time $t_x = l^2 \sqrt{t} \; x \; \sqrt{t_x}; \; 0.1 \leq t_x \leq 10 \; \text{ms}, \; V_{\text{RRM}} = 0 \; \text{V}$		7.9	11.3	kA²√s	
Low level of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), T _J maximum		0.76	0.77	V	
High level of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J$ maximum		0.89	0.92	v	
Low level forward slope resistance	r _{t1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J maximum		8.2	4.852	mΩ	
High level forward slope resistance	r _{t2}	$(I > \pi \times I_{F(AV)}), T_J$ maximum		6.8	3.867	1115.2	
Maximum forward voltage drop	V _{FM}	T _J = 25 °C, I _{FM} = I _{Favg (arm)}		1.1	1.1	V	
Maximum DC reverse current	I _{RRM}	$T_J = 25 \text{ °C}$, per diode at V_{RRM}		°C, per diode at V _{RRM} 5.0		μA	
RMS isolation voltage base plate	V _{INS}	f = 50 Hz, t = 1 s		2700		V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES GBPC25	VALUES GBPC35	UNITS
Junction and storage temperature range	T _J , T _{Stg}		-55 to +150		°C
Maximum thermal resistance, junction to case per bridge	R _{thJC}	DC operation	1.7	1.4	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.2		r./ vv
Approximate weight			16		g
Mounting torque ± 10 %		Bridge to heatsink	2.0		N · m (lbf · in)



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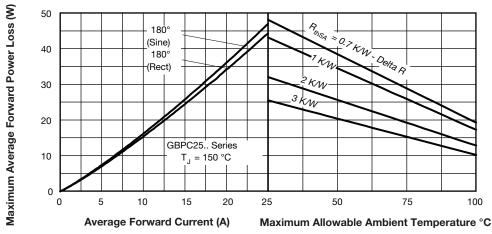
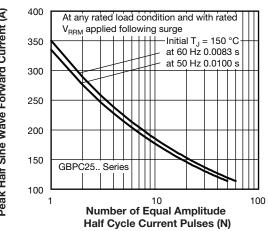


Fig. 3 - Total Power Loss Characteristics



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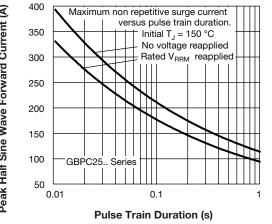


Fig. 5 - Maximum Non-Repetitive Surge Current

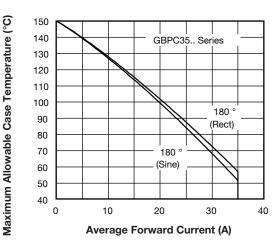
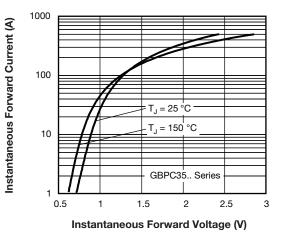


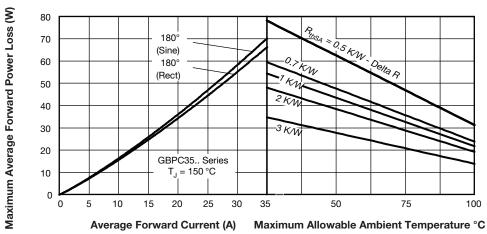
Fig. 6 - Current Ratings Characteristics



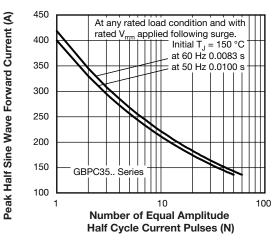


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Fig. 9 - Maximum Non-Repetitive Surge Current

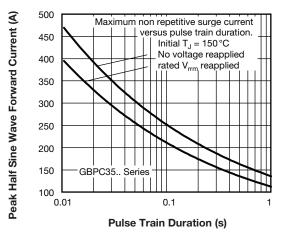
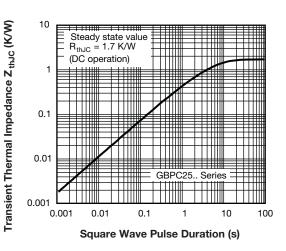
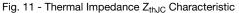


Fig. 10 - Maximum Non-Repetitive Surge Current





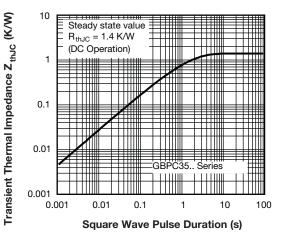


Fig. 12 - Thermal Impedance Z_{thJC} Characteristic

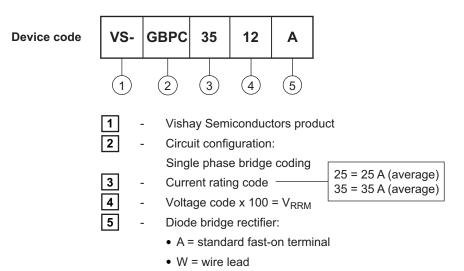
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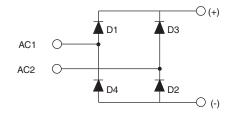
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95331			

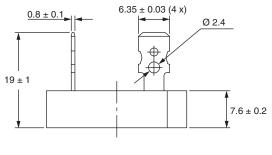
Outline Dimensions

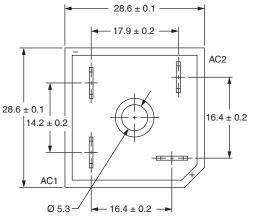




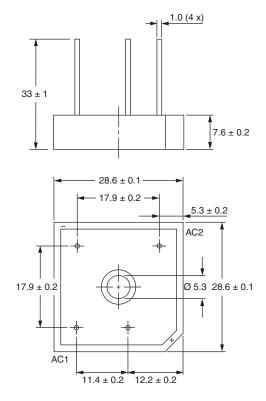
GBPC

DIMENSIONS FOR GBPC...A in millimeters





DIMENSIONS FOR GBPC...W in millimeters



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